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(54) **Infrared inspection system and method.**

(57) A device is analyzed by deriving first data representing temperature from pixels of the device while the device is being stimulated to emit infrared energy above a background level. The thus obtained first data are compared with second data stored in a computer representative of standard temperature from the pixels. A determination is made as to whether the first data for a particular pixel deviates from the second data for the pixel by a predetermined value in response to the comparisons at the different pixels to determine a property of the device. The device is indicated as being unacceptable in response to the deviation for a pixel being in excess of a predetermined value. The first data are derived for each pixel at plural times and the comparisons and determinations are made for the pixels at plural times. The life of the device is determined from the temperature of components on the device, as derived from the temperatures of the pixels.

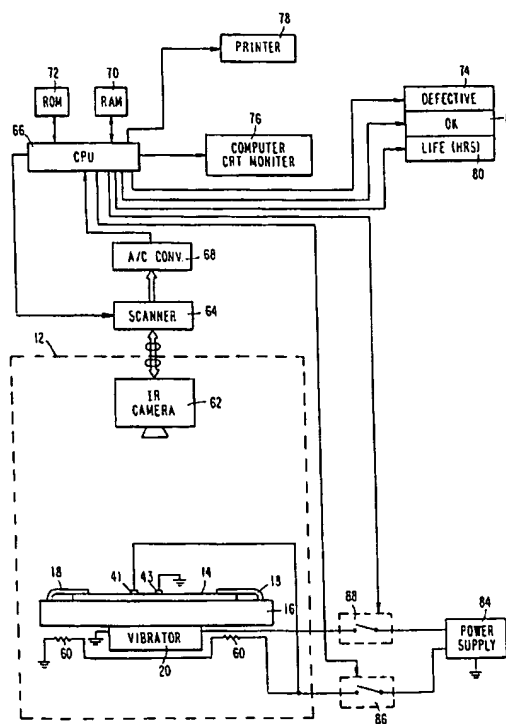


Fig. 1

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Field of Invention

The present invention relates generally to apparatus for and method of determining the presence and location of defects in manufactured items, and more particularly, to such a method and apparatus wherein an
 5 infrared image of the device, while stimulated, is derived from an infrared image and compared with a standard temperature image.

Background Art

10 Life-cycle methods have been previously used for determining the presence and location of defective parts and regions of a manufactured device by vibrating and temperature cycling the device for prolonged periods, typically about 48 hours. After the device has been life-tested by being vibrated and/or cyclically heated, it is inspected to determine defects by obtaining an infrared image of the device while the device is being stimu-
 15 lated. An infrared television camera supplies a signal to a color television monitor for deriving a multi-color image viewed by a human observer, who functions as an inspector for the device. Typically, hot and cold regions respectively appear on the monitor as the colors red and blue. The inspector is trained to recognize which areas should be red and which areas should be blue. Based on the inspector's training and the image on the monitor, the inspector decides whether a particular inspected device is defective or acceptable. In an automatic mode, a computer makes the decisions as to whether the device is acceptable.

20 In the prior art arrangement, the inspected life-tested device is environmentally stress screened by sine or random vibration, and/or by burn-in techniques. The environmental stress screening is used mainly to artificially improve reliability of a product by aging the product. However, the aging process actually reduces reliability because it fatigues marginal and sound parts of the device. Aging is the very characteristic which frequently accelerates wear of the product or device being tested or screened. Hence, with the prior art arrange-
 25 ment, there is a risk of damaging and weakening good parts and, in many cases, good parts are destroyed. Invariably, during this process, there is damage, to some degree, to all components having absolutely no flaw during manufacture.

The prior art arrangement is relatively expensive from initial capital and operational standpoints. The high capital cost is attributed to the expenses associated with the equipment for long term vibration, as well as heat-
 30 ing and cooling of every produced device. Temperature testing employs heaters and associated cooling mechanisms, custom temperature fixtures and associated electronic hardware for each tested assembly. A factor in the capital expense of a typical prior art arrangement is that the required floor space is usually in excess of 200 square feet. The high operational expense results from operating the vibration as well as heating and cool-
 35 ing equipment, in addition to the relatively slow product throughput associated with the time required to conduct prolonged vibration and/or elevated thermal tests and/or temperature cycling. The need for a highly trained human inspector for each produced device adds a considerable operational expense. The tested device must be powered up during temperature cycling. In both cases (vibration and temperature), a fixture for the tested device is aged, causing constant maintenance of the test fixture.

40 It is, accordingly, an object of the present invention to provide a new and improved apparatus for and method of inspecting and analyzing manufactured devices in response to the infrared energy emitted from the device while it is being stimulated.

45 An additional object of the invention is to provide a new and improved apparatus for and method of inspecting and analyzing manufactured devices and determining the worthiness thereof without subjecting the device to prolonged vibration and/or temperature cycling so that the tested device is not prematurely aged due to the inspection process.

An additional object of the invention is to provide a new and improved apparatus for and method of inspecting a manufactured part in such a manner that the inspection time is considerably reduced relative to the prior art.

50 A further object of the invention is to provide a new and improved relatively inexpensive apparatus for and method of testing manufactured devices for defects.

A further object of the invention is to provide a new and improved method of and apparatus for more accurately determining minor and major fault defects in manufactured devices.

55 An additional object of the invention is to provide a new and improved apparatus for and method of inspecting manufactured device which is easily incorporated into production lines and requires relatively little space in such lines.

Scanned x-ray systems were also previously used to determine the presence of defects in manufactured devices. In such systems, the device is effectively scanned by an x-ray source. A human observer notes the presence of cracks or other abnormalities and defects from an x-ray image of the device. Such systems are

expensive, and invasive of the device, as well as possibly the inspector and other personnel, with adverse effects on both.

An additional object of the invention is to provide a new and improved apparatus for and method of testing manufactured devices wherein the apparatus is completely passive to the product and personnel, so that there is no need for invasive devices such as x-rays.

Summary of the Invention

These and other objects are achieved in accordance with one aspect of the invention wherein a device is analyzed by deriving first data representing temperature from different regions of the device while the device is being stimulated to emit infrared energy above a background level. An indication of the infrared energy emitted from the different regions is combined with an indication of radiation emissivity from each region to derive the temperature representing data for each region. The thus-obtained first data are compared with second data stored in a computer representative of standard temperature for each of the different regions of the device. A determination is made as to whether the first data for a particular region deviate from the second data for the particular region by a predetermined amount for the particular region to determine a property of the device.

The device is indicated as being unacceptable, i.e., defective, in response to the deviation for a particular region being in excess of a predetermined value.

In a preferred embodiment of the invention the first data are derived for the same region at plural times and the comparisons and determinations are obtained for each of the regions at the plural times. The device is indicated as defective in response to the comparisons and determinations obtained for the regions being in excess of the predetermined value at any one of the plural times. By deriving the first data for the same region at plural times and performing the comparisons and determinations for the regions at the plural times, transient defects which would occur at the beginning of operation are detected.

To determine the standard temperature and radiation emissivity of the different regions of the device that are stored as the second data in the computer, many of the devices, e.g., 20, are life tested using the prior art vibration and thermal cycling methods. The intensity of infrared radiation emitted from different regions of each of the life tested devices, as well as from a standard emission target thereof, is determined for ambient conditions and while the device is at a slightly elevated temperature. These values are combined for corresponding regions of all the life-tested devices to determine the standard emissivity and temperature of each region.

In accordance with a further aspect of the invention, the above and other objects are attained by providing a device-analyzing apparatus including an infrared camera for monitoring infrared emission from the device and deriving a signal having magnitudes representing infrared emission from each of multiple pixels in a field of view of the camera. A computer responds to the signal to derive data representing the temperature at each of the pixels. The computer stores data representing standard temperatures from the device at each of the pixels. The computer compares the stored data and the data representing the temperature at each of the pixels of the device being tested to derive an indication of the deviation between the magnitude of the temperature at each pixel of the device with the temperature standard for each pixel. A property of the device is derived in response to the indication of the deviation at each pixel. In response to a deviation in excess of a predetermined value at any pixel, the device is indicated as being unacceptable. The signal from the infrared camera is derived for each pixel at least several times. A comparison is made of the deviation for each pixel at each of the times. The property is derived in response to the deviation indication for each pixel at each of the times.

The lifetime of the device is estimated in response to the infrared intensity from each pixel by deriving an indication of the average temperature of a component forming plural pixels. From the average temperature value, a measure of the expected temperature of the component during operation is derived. The indication of expected component temperature is combined with known data relating component lifetime with component temperature. The thus derived indications of lifetime for each component are combined to provide an indication of expected device lifetime. The expected device lifetime is compared with minimum acceptable values of device lifetime to determine if the device is acceptable and to grade the device for different purposes, e.g., different price ranges.

In accordance with a further aspect of the invention, the thermal emissivity at multiple pixels on a surface is determined by monitoring the infrared emission at each pixel, as well as from a target on the surface having a standard thermal emissivity; these measurements are made at a first temperature, e.g., at ambient temperature. The same measurements are made with the device at a second temperature displaced by a predetermined amount, such as 5°C, from the first temperature. The ratio of the emission from each pixel at the first temperature relative to the emission from the standard material target at the first temperature is determined. Each of these ratios is divided by the known emissivity of the standard material to determine a measure of the temperature of each pixel while the device is at the first temperature. A measure of the temperature of each

pixel while the device is at the second temperature is determined in the same manner. An emissivity correlation coefficient is calculated for each pixel in response to infrared emission at each pixel for ambient and elevated temperatures and emissivity of the standard target material. These values are combined for all of the life-tested devices to provide an emissivity correlation correction that is a measure of average temperature of each pixel of all of the life-tested devices.

The emissivity correlation correction coefficient for each pixel is then corrected for the first temperature value and the absolute temperature for each pixel is determined. To determine the absolute temperature of each pixel of a tested device, the emissivity of the pixel, as determined from the standards, is combined with the measured intensity of the infrared energy emitted from the pixel, as detected by the infrared camera responding to infrared radiation at the first and second temperatures. Alternatively, the temperature of a pixel can be determined by using standard emissivity tables for a particular material in a particular pixel and combining the standard emissivity value with the monitored infrared emission intensity from the pixel.

The above and still further objects, features and advantages of the present invention will become apparent upon consideration of the following detailed description of an embodiment thereof, especially when taken in conjunction with the accompanying drawings.

Brief Description of Drawing

Fig. 1 is a schematic mechanical and electrical diagram of a preferred embodiment of the present invention;
 Fig. 2 is a view of a printed circuit assembly of the type monitored with the apparatus of Fig. 1;
 Fig. 3 is a flow diagram of operations performed by the apparatus of Fig. 1 on printed circuit assemblies that have been life-tested to enable the standard data to be derived; and
 Fig. 4 is a flow diagram of operations performed by the apparatus of Fig. 1 on printed circuit assemblies being tested to determine if the printed circuit assemblies are acceptable and the expected life of the assemblies.

Description of the Preferred Embodiment

Reference is now made to Fig. 1 of the drawing wherein a device to be tested is located in thermally stable chamber 12. In the specific embodiment described, the tested device is printed circuit assembly 14, Fig. 2, formed as a DC amplifier including transistors 16, 18 and 20, as well as resistors 21-32, all of which are connected to each other by aluminum strips 40-50 deposited on dielectric substrate 52, which also includes target 54 fabricated of a material having a known, precise and stable thermal emissivity coefficient. Printed circuit assembly 14 is mounted on mounting fixture 16 by spring fingers 18. Mounting fixture 16 is mechanically connected to mechanical vibrator 20 and placed in proximity to electric heating devices 60, located within chamber 12. (While device 60 is shown as a resistance heater, it is to be understood that separate heaters are not necessary and that the function of heaters 60 is preferably performed by electric devices in chamber 12 that are turned on and off during operation of the device.)

Infrared radiation radiated from the face of printed circuit assembly 14 opposite from the face of the printed circuit assembly in contact with fixture 16 is monitored by infrared camera 62, mechanically driven up and down relative to printed circuit assembly 14, as well as in X and Y coordinate directions in a plane at right angles to the exposed face of printed circuit assembly 14. Such movements of camera 62 are provided by conventional drive structures (not shown). Camera 62 also includes a zoom lens feature to enable different regions of printed circuit assembly 14 to be monitored with greater resolution than other regions of the printed circuit assembly. While camera 62 is monitoring printed circuit assembly 14 the camera is maintained in a stationary condition.

Camera 62 derives a set of signals, one for each region, i.e. pixel, of printed circuit assembly 14 and indicative of the intensity of the infrared radiation emitted from the pixel. Camera 62 is preferably of a type including a separate target for each pixel on the exposed face of printed circuit assembly 14. The intensity of the infrared radiation emitted from each pixel of printed circuit assembly 14 is determined by supplying the signal from each target region of infrared camera 62 to multiplexing scanner 64, addressed in a conventional manner by signals from central processing unit (CPU) 66. Scanning multiplexer 64 supplies a sequence of signals at displaced time intervals to analog to digital converter 68; the signals represent the intensity of infrared radiation emitted from each pixel of printed circuit assembly 14. Converter 68 supplies digital signals to CPU 66. The digital signals supplied by converter 68 are routed by CPU 66 to random access memory (RAM) 70. CPU 66 includes an internal program to control the flow of data from converter 68 to RAM 70 and from RAM 70 back to the CPU, as described infra. CPU 66 is also responsive to table look-up information stored in read-only memory (ROM) 72.

CPU 66 responds to the signals from infrared camera 62 indicative of the infrared emission from the pixels

of printed circuit assembly 14, as well as signals from RAM 70 and ROM 72, to derive signals indicative of the temperature of each pixel. The signals indicative of each pixel temperature are combined with standard values for the temperature at each pixel to determine if a particular pixel has an excessively high or low temperature while printed circuit assembly 14 is being vibrated by vibrator 20 and heated by heaters 60. In a preferred embodiment, 80 milliseconds are required to examine all of the pixels of printed circuit assembly 14. One such 80 milliseconds time interval is referred to herein in as a scan period. Each printed circuit assembly 14 is examined over at least several scan periods, typically for about one to two seconds. If any pixel in any of the scan periods has a temperature above or below a predetermined value, CPU 66 derives a signal indicating the printed circuit assembly as being defective; such a signal after being stored in RAM 70 is supplied to DEFECTIVE visual indicator output 74 and to printer 78 with an indication of the identity of the defective assembly number.

The deviation in temperature of each pixel from the standard value therefor is supplied, at the end of each scan period, by CPU 66 to computer cathode ray tube (CRT) monitor 76. Monitor 76 can be either a black and white monitor, showing pixel deviation in gray-scale so there is a spatial correlation between the image on the monitor and the pixels of printed circuit assembly 14 monitored by camera 62. Alternative, monitor 76 can be a color display wherein pixels having temperatures in excess of and less than the standard values are respectively indicated by differing shades of red and blue; the intensity of the red and blue pixel images on CRT monitor 76 increases as the temperature deviates by greater amounts from the standard value therefor. The gray scale values are converted into color intensities by a look-up table included in ROM 72. Computer CRT monitor 76 thus provides a spatial representation of the pixels on printed circuit assembly 14 that deviate in temperature from the standard temperature of the pixel. If a particular pixel of printed circuit assembly 14 is at a temperature exactly equal to the standard temperature for that pixel, a neutral color appears at the corresponding pixel on monitor 76.

CPU 66 also responds to the signals from IR camera 62 and ROM 72 to derive indications of the expected life of each component on printed circuit assembly 14. Each component occupies at least several predetermined pixels on printed circuit assembly 14. The average temperature of the pixels on printed circuit assembly 14 where the components, e.g., transistors 16-20 and resistors 21-32, are located is determined from the intensity of the infrared radiation monitored by camera 62. From the temperatures resulting from the monitored infrared energy for the pixels of a particular component and stored values in ROM 72, the expected life of a particular component is determined. The expected component life is compared with a minimum life (in hours) of the component. If the comparison indicates the expected component life is less than the minimum required component life, the printed circuit assembly is indicated as being defective and printer 78 is activated to indicate the particular component is defective. The component can, thereby, easily be removed and the printed circuit assembly re-worked appropriately.

The life of printed circuit assembly 14 is determined by CPU 66 in response to signals from RAM 70 and ROM 72 by combining the indications of the expected life of all of the components. The expected life of the printed circuit assembly thus determined is compared by CPU 66 with a minimum acceptable expected printed circuit assembly life. If CPU 66 determines that the life of printed circuit assembly 14 is less than a predetermined duration, CPU 66 supplies a signal to DEFECTIVE visual indicator output 74 and to printer 78. The expected life of printed circuit assembly 14 is supplied by CPU 66 to printer 78, as well as to LIFE numerical read-out 80. If all of the pixels, components and printed circuit assembly 14 as a whole have expected temperature values and lifetimes in conformance with established standards, CPU 66 supplies a signal to OK output 82, as well as to printer 78.

CPU 66 responds to its internal program to control the application of energy from power supply 84 to vibrator 20 and heater 60. To this end, CPU 66 supplies separate signals to contacts 86 and 88, causing closure thereof to connect power supply 84 to heaters 60 and vibrator 20, respectively. When contacts 86 are closed, power is supplied to aluminum strips 41 and 43 on printed circuit assembly 14 to stimulate operation of the amplifier on printed circuit assembly 14. Connections are made to strips 41 and 43 by machinery (not shown) automatically controlling conveying of printed circuit assemblies 14 onto vibrator 16 or such connections can be made manually.

In a manufacturing facility, printed circuit assemblies 14 are automatically supplied to fixture 16 by a conveyor structure (not shown). Each printed circuit assembly 14 includes a standard bar code for identification purposes to enable data to be collected and stored by CPU 66 and RAM 70 for all of the monitored printed circuit assemblies. Alternatively, the printed circuit assemblies can be manually inserted on spring fingers 18 of fixture 16.

Standards for the temperature at each pixel of the monitored, manufactured printed circuit assemblies are established by supplying an appropriate number, e.g., 20, satisfactory life-tested printed circuit assemblies identical to the monitored printed circuit assemblies to fixture 16. The intensity of the infrared radiation emitted

from each pixel for each of the life-tested assemblies is monitored by infrared camera 62 and coupled to CPU 60, thence to RAM 70. The average value of the intensity at each pixel for all of the life-tested printed circuit assemblies is determined and compared with the intensity of the infrared radiation emitted from standard target material 54. The emissivity at each pixel is thereby determined. The emissivity values for the pixels are combined with the radiation intensity indications from the monitored printed circuit assemblies to determine the temperature at each monitored pixel of each tested printed circuit assembly.

Prior to considering the computer program stored by CPU 66 to determine the properties of printed circuit assembly 14 and supply signals indicative thereof to output devices 70 and 74-82, further consideration is given to Fig. 2. In Fig. 2, pixels $P_{x,y}$ are illustrated as being superimposed on printed circuit assembly 14 such that pixel $P_{1,1}$ is in the upper left-hand corner and pixel $P_{m,n}$ is in the lower right-hand corner. In one preferred embodiment, $M = 192$, and $N = 100$ so that there are 19,200 square, equal-area pixels in the field of view of infrared camera 62. Camera 62 includes a scanning detector for each of the 19,200 pixels. In the simplified situation illustrated in Fig. 2, target region 54 having a precise, known stable thermal emissivity is located at pixel $P_{2,3}$. Resistor 21, having a rectangular shape in the field of view of camera 62, occupies pixels $P_{2,6}$ - $P_{2,8}$. The remaining components, i.e., transistors and resistors, on printed circuit assembly 14 occupy precise pixels so that the areas thereof in the field of view of camera 62 are known.

Reference is now made to Fig. 3 of the drawing, a flow diagram of operations and computations performed by the apparatus to determine standard emissivity of each pixel on each of the life-tested printed circuit assemblies, as well as the standard absolute temperature of each pixel of a printed circuit assembly during operation. The operations of Fig. 3 are performed in sequence on each of many, e.g., 20, life-tested printed circuit assemblies identical to the printed circuit assemblies of Fig. 2. As indicated supra, the life-tested printed circuit assemblies are supplied in sequence to fixture 16.

The first operation 102 of the standard computation, after a life-tested printed circuit assembly has been loaded onto fixture 16, is to identify the number of the life-tested printed circuit assembly being monitored and to initialize operations. The identification of the life-tested printed circuit assembly is determined by directing infrared camera 62 at the region on the printed circuit assembly where the bar code identification (not shown) for the printed circuit assembly is located. The bar code information is read by camera 62 into an appropriate address in RAM 70 under the direction of CPU 66. CPU 66 then supplies a signal to command closure of switch 88 causing vibrator 20 to be activated by power supply 84.

Computer 66 then (during operation 103) directs infrared camera 62 to pixel $P_{2,3}$ where standard emission target 54 is located. The intensity of the infrared radiation from target 54 while printed circuit assembly 14 is at ambient temperature, $I_{STD(AMB)}$, is then determined by IR camera 62 deriving an analog signal indicative of this value. The signal for target 54 derived by camera 62 is supplied by scanner 64 to analog-to-digital converter 68. The digital output of converter 68 is supplied by CPU 66 to a designated address in RAM 70. The intensity of the radiation emitted by target 54, $I_{STD(AMB)}$, stored in RAM 70 is combined with the known radiation emissivity of target 54, as stored in ROM 72, ϵ_{STD} . CPU 66 responds to $I_{STD(AMB)}$ and ϵ_{STD} to derive the product $I_{STD}\epsilon_{STD}$. These steps are performed during operation 104.

Then (during operation 106) the intensity of the infrared radiation from the first pixel of the printed circuit assembly while the assembly is at ambient temperature is determined. To these ends, CPU 66 supplies a signal to scanner 64 to command read-out of infrared camera 62 from pixel $P_{1,1}$ for printed circuit assembly 14.

The computer program then advances to operation 108, during which infrared camera 62 is commanded to read the intensity $I_{x,y(AMB)}$ of the infrared energy emitted from pixel $P_{x,y}$ while assembly 14 is at ambient temperature. Initially, pixel $P_{x,y}$ is pixel $P_{1,1}$ as a result of the address supplied by CPU 66 to scanner 64. The ambient infrared intensity from each of the various pixels is read in sequence with the values of x increasing until the last value of $x = M$ is reached; then CPU 66 increments y to command scanner 64 to read pixel $P_{1,2}$. The intensity of the infrared energy emitted from all of the pixels is read by camera 62 and stored in designated addresses of RAM 70. The scanning steps are indicated by operations 109, 110, 111, 112 and 113. During operations 112 and 113, the values of x and y are incremented by 1 to provide shifts in the values of x and y .

A measure of the temperature of each pixel while printed circuit assembly 14 is at ambient temperature is calculated during operation 108, after the intensity of the infrared energy for a particular pixel has been determined in accordance with:

$$B = \frac{I_{x,y(AMB)}}{I_{STD(AMB)}\epsilon_{STD}} \quad (1)$$

All of operations 102-108 are performed at ambient temperature in chamber 12. After operation 109 has determined that the last pixel of a particular life-tested printed circuit assembly has been read by infrared camera 62, the program advances to operation 114 during which CPU 66 commands closure of contacts 88 causing current to be supplied by power supply 84 to heaters 60, as well as strips 41 and 42. This causes heating and

the application of power to the life-tested printed circuit assembly in the field of view of infrared camera 62. Heaters 60, when energized, typically raise the temperature of the printed circuit assembly 5°C.

CPU 66 then (during operation 115) commands scanner 64 to cause IR camera 62 to address standard pixel 54, followed by the first pixel $P_{13,1}$ on the life-tested printed circuit assembly being examined. After operation 115, CPU 66 commands IR camera 62 to read the intensity of the radiation from the multiple pixels of printed circuit assembly 14 in the same manner as described for ambient temperature operations; operations 116-121. During operation 116, the elevated temperature of each monitored pixel while the printed circuit assembly is at an elevated temperature is determined in accordance with:

$$C = \frac{I_{x,y(AMB + \delta T)}}{I_{STD(AMB + \delta T)} \epsilon_{STD}} \quad (2)$$

where:

$I_{x,y(AMB + \delta T)}$ = the intensity of infrared radiation from pixel x,y at the elevated temperature of printed circuit assembly 14; and

$I_{STD(AMB + \delta T)}$ = the intensity of infrared radiation from target 54 at the elevated temperature of printed circuit assembly 14.

The values of B and C as calculated by CPU 66 during operations 108 and 116 are stored in designated addresses of RAM 70.

After the last pixel of a particular life-tested printed circuit assembly has been read, as determined during operation 117, the program advances to operation 122 during which CPU 66 commands contacts 86 and 88 to open so vibrator 20 and heaters 60 are de-energized. After operation 122, the program advances to program 123, when a determination is made as to whether the particular life-tested printed circuit assembly is the last life-tested assembly to be analyzed to determine standard temperature values for each pixel. In response to operation 123 indicating that there are remaining life-tested printed circuit assemblies to be monitored to define the standard temperature values, the program advances to operation 124, when the number (q) of the life-tested printed circuit assembly is incremented by 1. Then, the program advances to operation 125 when a command is given to insert a different life-tested printed circuit assembly into fixture 16. After operation 125, the program returns to operation 102 and the previously described sequence is repeated until all of the life-tested printed circuit assemblies used to accumulate the standard temperature data have been monitored by infrared camera 62.

In response to operation 123 indicating that the last life-tested printed circuit assembly (Q) forming the standard has been monitored by camera 62, i.e., $q = Q$, the program of CPU 66 advances to operation 126. During operation 126, the absolute temperature for each pixel of all of the life-tested monitored printed circuit assemblies is calculated. To determine the standard absolute temperature for each pixel, a correlation correction coefficient for the ambient and elevated temperatures of printed circuit assembly 14 is determined for each pixel in accordance with:

$$r(B, C) = \frac{\sum_{q=1}^Q |B_q - \bar{B}| \cdot |C_q - \bar{C}|}{Q \cdot S_B \cdot S_C} \quad \dots (3)$$

where Q, B and C have previously been defined,

\bar{B} = the average value of B at the particular pixel for all of the Q life-tested printed circuit assemblies,

\bar{C} = the average value of C at the particular pixel for all of the Q life-tested printed circuit assemblies,

S_B = the standard deviation of the values of B at the particular pixel for the Q life-tested printed circuit assemblies, and

S_C = the standard deviation of the values of C at the particular pixel for the Q life-tested printed circuit assemblies.

The corrected absolute temperature for each pixel is then computed as:

$$TC = B \cdot r(B, C) \quad (4)$$

Then, during operation 126, a gray-scale correction correlation factor is determined for each pixel in accordance with:

$$\text{Gray - scale} = \frac{(TU - TL)}{\text{Number of gray - scale steps}} \quad (5)$$

where:

TU is an upper temperature detection limit of infrared camera 62, and

TL is a lower temperature detection limit for infrared camera 62.

Typically, $T_U = 50^\circ\text{C}$, $T_L = 20^\circ\text{C}$, and the number of gray-scale steps is 256.

Then, during operation 126, the absolute temperature value for each pixel is determined as:

$$T_{gs} = (TC \cdot \text{gray} - \text{scale})TL \quad (6)$$

The values of T_{gs} for each pixel, after being calculated by CPU 66, are stored in designated addresses of RAM 70.

After operation 126, the standard computation program is exited. Data resulting from the standard computation program stored in RAM 70 are combined with signals from infrared camera 62 when the camera is viewing printed circuit assemblies 14 in chamber 12 to determine the acceptability and lifetime of the printed circuit assemblies. The operations and computations required to determine the acceptability and lifetime (in hours) of manufactured printed circuit assemblies, without going through a life-test, are illustrated in Fig. 4.

Fig. 4 is a flow diagram of operations performed by the apparatus of Fig. 1 on printed circuit assemblies 14 during production to determine whether the printed circuit assembly is defective, whether components on the printed circuit assembly are defective, and the life of the printed circuit assembly. After a printed circuit assembly has been loaded onto fixture 16 and while the printed circuit assembly is subjected to vibration for a few seconds, the intensity of infrared radiation and from each pixel on the printed circuit assembly is determined at ambient conditions, in the same manner as discussed *supra*, for operations 102-112. Heat and power are then applied to the vibrating printed circuit assembly by energizing heaters 60 and connecting power supply voltage to aluminum stripes 41 and 43 on printed circuit assembly 14, as described *supra* for operation 114. The intensity of infrared radiation emitted from each of the pixels of the tested printed circuit assembly is then monitored during each of several scanning periods. During one of the scanning periods, intensity is monitored in the same manner as indicated *supra* in connection with operations 115-117. After each scanning period, a determination is made during operation 130 as to whether the last scanning period, T_F , has been reached for each particular printed circuit assembly being monitored. If the last scanning period has not been reached, the scanning period value, t , is incremented during operation 131 and the intensity of the infrared radiation from each of the pixels is again determined. Each of the values of radiation intensity for each of the pixels for each of the scanning periods is stored in RAM 70.

In response to operation 130 indicating completion of the last scan period, i.e., $t = T_F$, vibrator 20 and heaters 60 are de-energized and power is removed from stripes 41 and 43 during operation 132. Fixture 16 is thus prepared to receive another printed circuit assembly.

Then, during operation 133, the absolute temperature for each pixel for each scanning period of the tested device is determined by using a similar set of equations as used to provide a measure of the absolute temperature of each pixel of the standard. The values of B and C for each of the pixels and all of the scanning periods of each manufactured, tested printed circuit assembly are determined in accordance with Equations (1) and (2). The correlation correction coefficient for each pixel and all of the scanning periods (t) of each tested printed circuit assembly is determined as:

$$r_{\text{tested}}(B, C) = \frac{|B_t - \bar{B}| \cdot |C_t - \bar{C}|}{S_B \cdot S_C} \quad (7)$$

where:

B_t is the value of B for the pixel during scanning period t ,

C_t is the value of C for the pixel during scanning period t , and

\bar{B} , \bar{C} , S_B and S_C are determined during the operations of Fig. 3.

The absolute temperature value for each tested pixel during each scan period is determined from the values of $r_{\text{tested}}(B, C)$ and B for the tested pixel in accordance with:

$$T_{\text{test}} = B_t \cdot r_{\text{tested}}(B, C) (\text{Gray} - \text{scale}) + TL \quad (8)$$

After the absolute temperature for each pixel during each scan period is determined, a measure of the deviation of the temperature for each pixel (T_{test}) from the desired value therefor (T_{gs}), as determined during the operations of Fig. 3, is made during operation 134 in accordance with

$$|\Delta T| = |T_{gs} - T_{\text{test}}| \quad (9).$$

A determination is then made during operation 135 as to whether $|\Delta T|$ is greater than ΔT_{max} (where ΔT_{max} is a predetermined value stored in ROM 72 for each pixel and may differ from pixel to pixel) for each pixel during each scanning period. In response to operation 135 indicating that $|\Delta T|$ for a particular pixel during a particular scan period exceeds ΔT_{max} DEFECTIVE output 74 is energized and printer 78 is activated to indicate which pixel is defective during which scan period; these steps are performed during operation 136.

After operation 136 or in response to operation 135 providing a "no" result, the average temperature for each component on printed circuit assembly 14 is calculated during operation 137. The average temperature for each component is computed by determining the temperature during the last scan period, T_F , of each pixel occupied by the component. The temperatures at all of the pixels where a particular component is located are

added and divided by the number of pixels the component occupies to determine average component temperature. The thus-determined component temperature value is increased to the expected operating ambient temperature of printed circuit assembly 14, in use. The expected temperature for each component is then compared with a standard maximum temperature for each component, stored in ROM 72; these steps are indicated
 5 by operation 138. In response to operation 138 indicating that a particular component has an expected operating temperature in excess of the maximum- operating temperature for that component, the program advances to operation 139, during which DEFECTIVE output 74 is energized and printer 78 is activated to indicate the defective component on printed circuit assembly 14.

After operation 139 or a "no" response from operation 135, the lifetime of each component is determined
 10 during operation 140 by supplying the indication of component operating temperature calculated during operation 137 to a look-up table in ROM 72. The look-up table correlates the life of each component in hours, as determined from the component manufacturer, with expected operating temperature.

The lifetime of printed circuit assembly 14 is then computed during operation 141 by combining the component lifetimes derived during operation 140 in accordance with:

$$R_e = R_1 \cdot R_2 \cdot R_3 \dots (\text{etc}) \quad (10)$$

where:

R_1 is a measure of the lifetime of a first component on printed circuit assembly 14;

R_2 is a measure of the lifetime of a second component on printed circuit assembly 14; and

R_3 is a measure of the lifetime of a third component on printed circuit assembly 14.

20 The value computed during operation 141 is supplied, with the number of the printed circuit assembly, to printer 78 and then compared during operation 145 with a minimum lifetime for assembly 14. In response to the computed lifetime being less than the minimum lifetime value stored in RAM 72, DEFECTIVE output 74 is energized during operation 146.

After operation 146 or a "no" from operation 145, the program advances to operation 142 when a determination is made as to whether the printed circuit assembly just previously monitored is the last printed circuit assembly in the line. In response to a "yes" being derived during operation 142, the program is exited. In response to a "no" being derived during operation 142, the number of the printed circuit assembly handled is incremented during operation 143. Then, a new printed circuit assembly to be monitored is loaded onto fixture 16, as indicated by operation 144. The new printed circuit assembly is loaded automatically in the preferred
 30 embodiment, although such loading can be manual, in which case a visual signal is supplied to an operator by the apparatus illustrated in Fig. 1.

While there has been described and illustrated one specific embodiment of the invention, it will be clear that variations in the details of the embodiment specifically illustrated and described may be made without departing from the true spirit and scope of the invention as defined in the appended claims.

Claims

1. A method of analyzing a device comprising the steps of monitoring infrared emission from different regions
 40 of the device while the device is being stimulated to emit infrared energy above a background level, responding to the emission from the different regions to derive first data representing the temperature at the different regions, comparing the thus-obtained first data with second data stored in a computer representative of standard temperature of the different regions of the device, and determining whether the first data for a particular region deviates from the second data for the particular region by a predetermined
 45 value for the particular region in response to the comparisons at the different regions to determine a property of the device.
2. The method of claim 1 wherein the device is indicated as being unacceptable in response to the deviation for a particular region being in excess of a predetermined value.
3. The method of claim 2 wherein the emission is monitored from each region at plural times, the first data
 50 being derived for the same region in response to the monitoring at the plural times, the comparisons and determinations being obtained for the regions at the plural times, the device being indicated as unacceptable in response to the comparisons and determinations obtained for the regions being in excess of the
 55 predetermined value during any of the plural times.
4. The method of claim 1 wherein the emission is monitored from each region at plural times, the first data being derived for the same region in response to the monitoring at the plural times, the comparisons and

determinations being obtained for the regions at the plural times, the device being indicated as unacceptable in response to the comparisons and determinations obtained for the regions being in excess of the predetermined value during any of the plural times.

- 5 5. Apparatus for analyzing a device comprising an infrared camera for monitoring infrared emission from the device and for deriving a signal having magnitudes representing the infrared emission from each of multiple pixels in a field of view of the camera, a computer responsive to the signal including: means for storing data representing standard temperature of the device at each of the pixels, means for: (a) combining indications of the infrared emission from each pixel and an emissivity indication of each pixel to derive an indication of monitored temperature of each pixel, (b) comparing the stored data and the indications of monitored temperature of each pixel, and (c) deriving an indication of the deviation between the magnitude of the standard temperature and monitored temperature at each pixel; and means responsive to the indication of the deviation at each pixel for indicating a property of the device.
- 10 6. The apparatus of claim 5 wherein the means for indicating includes a two-dimensional display for displaying an image of the deviation at each pixel, the image spatially corresponding with an image of the device.
- 15 7. The apparatus of claim 6 wherein the means for indicating responds to a deviation in excess of a predetermined value at any pixel for signalling that the device is unacceptable.
- 20 8. The apparatus of claim 5 wherein the signal is derived for each pixel at plural times, the computer deriving the deviation indication for each pixel at each of the plural times, the property indicating means responding to the deviation indication for each pixel at each of the plural times.
- 25 9. A method of detecting the temperature of a region on a structure having an area with known radiation emissivity, the area being displaced from the region, the region having a tendency to be at a temperature displaced from the temperature of the structure as a result of a stimulus being applied to the region, comprising detecting the intensity of infrared radiation emitted from the region and the area while the structure is at first and second displaced temperatures, and combining indications of (a) the detected intensity from the region and the area while the structure is at said temperatures and the stimulus is applied to the region while the structure is at one of the temperatures, and (b) the known emissivity, the indicating being combined such that there is derived an indication of the temperature of the region while the structure is at said one temperature and the stimulus is applied to the region.
- 30 10. The method of claim 9 wherein the method is performed to derive a standard temperature for the region by performing said steps on Q structures having corresponding ones of said areas and regions, where Q is at least several, deriving indications of the detected intensities from the corresponding regions and areas of the Q structures, and combining the derived indications of the detected intensities from the corresponding areas and regions of the Q structures to derive an indication of the standard temperature of the region while the structure is at said one temperature and the stimulus is applied to the region.
- 35 40 11. The method of claim 10 wherein the indication of the standard temperature for the region is derived in response to

$$B = \frac{I_{T1}}{I_{STD1} E_{STD}}$$

$$C = \frac{I_{T2}}{I_{STD2} E_{STD}}$$

$$r(B, C) = \frac{\sum_{q=1}^Q |B_q - \bar{B}| \cdot |C_q - \bar{C}|}{Q \cdot S_B \cdot S_C}$$

where:

I_{T1} = intensity of radiation from the region at the first temperature

I_{T2} = intensity of radiation from the region at the second temperature

I_{STD1} = intensity of radiation from the area at the first temperature

I_{STD2} = intensity of radiation from the area at the second temperature

ϵ_{STD} = known radiation emissivity of the area
 Q = the number of the at least several structures
 q = is successively each of 1, 2... Q
 \bar{B} = average value of B for the Q structures
 \bar{C} = average value of C for the Q structures
 S_B = standard deviation of B for the Q structures
 S_C = standard deviation of C for the Q structures.

12. The method of claim 11 wherein the steps of claim 9 are also performed on a region of a monitored structure corresponding with the region for which the standard temperature is derived and on an area of the monitored structure having a known thermal emissivity, deriving an indication of the temperature of the corresponding region on the monitored structure in response to

$$r_{tested}(B,C) = \frac{|B_{test} - \bar{B}| \cdot |C_{test} - \bar{C}|}{S_B \cdot S_C}$$

where

$$B_{test} = \frac{I_{T1(test)}}{I_{STD1(test)} \epsilon_{STD}}$$

$$C_{test} = \frac{I_{T2(test)}}{I_{STD2(test)} \epsilon_{STD}}$$

$I_{T1(test)}$ = intensity of radiation from the region of the monitored structure at the first temperature
 $I_{T2(test)}$ = intensity of radiation from the region of the monitored structure at the second temperature
 $I_{STD1(test)}$ = intensity of radiation from the area of the monitored structure at the first temperature
 $I_{STD2(test)}$ = intensity of radiation from the area of the monitored structure at the second temperature.

13. The method of claim 12 wherein an indication of standard temperature for the region is derived in response to $B \cdot r(B,C)$ and an indication of temperature for the region of the monitored structure is derived in response to $B_{test} \cdot r_{tested}(B,C)$, and determining the deviation between the indications of standard temperature for the region and temperature for the region of the monitored structure.

14. The method of claim 11 wherein the indication of the standard temperature for the region is obtained by (a) determining first and second measures of the average infrared intensity from the corresponding regions of the at least several structures at said first and second temperatures, (b) determining a third measure of the deviation of the infrared intensity from the region of each of the structures at the first temperature from the first measure, (c) determining a fourth measure of the deviation of the infrared intensity from the region of each of the structures at the second temperature from the second measure, (d) non-linearly combining the third and fourth measures for each of the structures to derive a first resultant, (e) linearly combining the first resultants for the at least several structures to derive a second resultant, (f) determining first and second indications of the spread of values of the detected intensities from the regions at the first and second temperatures, respectively, and (g) combining the second resultant with the first and second indications.

15. The method of claim 10 wherein the indication of the standard temperature for the region is obtained from a statistical function of (a) a value of the known emissivity and (b) the detected intensities at the areas and regions of the Q structures while the structures are at the first and second temperatures.

16. The method of claim 15 wherein a value derived from the statistical function is combined with a measure of the detected intensity for the region to provide an indication of the standard temperature for the region.

17. The method of claim 16 wherein the statistical function value is derived by determining the average values and the standard deviations of the intensities from the corresponding regions of the Q structures at the first and second temperatures, and combining the determined average values and standard deviations.

18. The method of claim 10 wherein the steps of claim 9 are also performed on a region of a monitored structure corresponding with the region for which the standard temperature is derived and on an area of the monitored structure having a known thermal emissivity, deriving an indication of the temperature of the corresponding region on the monitored structure in response to indications of (a) the intensity of the infrared radiation from the corresponding regions and the areas of the Q structures at the first and second

temperatures thereof, (b) the emissivity of the areas of the Q structures, (c) the intensity of the infrared radiation from the corresponding region and the area of the monitored structure at the first and second temperatures thereof, and (d) the emissivity of the area of the monitored structure.

- 5 **19.** The method of claim 18 further including combining the indications of the temperatures of the corresponding regions of the monitored and standard structures and the Q structures to determine the deviation of the temperature of the region of the monitored structure from the temperature of the region of the monitored standard.
- 10 **20.** A method of detecting the expected lifetime of a device including plural components comprising the steps of monitoring the intensity of infrared radiation emitted from the components while the components are stimulated to a higher temperature than ambient temperature of the device, combining a first indication of the monitored radiation from each particular component with an indication of the particular component radiation emissivity to derive an indication of expected operating temperature of each particular component, responding to the indication of expected operating temperature of each particular component and
15 a stored value relating expected operating temperature of each particular component to the lifetime of the particular component to derive a second indication representing the expected lifetime of each particular component, and combining the second indications for all of the components to derive the indication of the device lifetime.
- 20 **21.** The method of claim 20 wherein the intensity of the infrared radiation is monitored for at least several pixels on the device, each of the components occupying a plurality of said pixels having known locations on the device, the temperature indication of each particular component being derived by combining indications of (a) the monitored radiation intensity from all of the pixels occupied by the particular component and
25 and (b) the radiation emissivity of the pixels occupied by the particular component.
- 22.** The method of claim 21 wherein the intensity of the infrared radiation for the pixels is monitored while the device is at first and second displaced temperatures, and further including monitoring the intensity of infrared radiation emitted from an area of the device while the device is at the first and second temperatures, the area having known radiation emissivity, and combining indications of the monitored intensity of the infrared radiation of the pixels and the area while the device is at the first and second temperatures with an indication of the emissivity of the area to provide an indication of the temperature of each pixel.
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- 23.** A method of analyzing a device comprising the steps of monitoring the intensity of infrared emission from different spaced regions of the device while the device is being stimulated to emit infrared energy different from a background level, responding to the monitored intensity of the infrared emission from the different spaced regions to derive data representing the temperature at the different spaced regions, and responding to the derived temperature data for the different spaced regions to derive an indication of worthiness of the device for its intended use.
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- 24.** The method of claim 23 wherein the temperature data for each region are derived by combining an indication of the intensity of the monitored emission from each region with an indication of the radiation emissivity for each region.
- 45 **25.** The method of claim 24 wherein the indication of the radiation emissivity for each region is derived by monitoring at first and second displaced temperatures of the device while the regions are stimulated the intensity of infrared radiation from (a) each region and (b) an area on the device having known radiation emissivity, and deriving a measure of the temperature for each particular region by combining (a) the monitored intensities for the particular region and the area at the different temperatures and (b) the known radiation emissivity.
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- 26.** The method of claim 24 wherein each of the regions is formed as a pixel, the method also being performed to determine the lifetime of each of plural components on the device, the method further comprising stimulating the components to a temperature above the device background temperature while the emission is being monitored, each of the components occupying a plurality of said pixels having known locations on the device, deriving an indication of the expected operating temperature of each component by combining indications of (a) the intensity of monitored emission from all of the pixels occupied by the particular component and (b) the radiation emissivity of the pixels occupied by the particular component, responding
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to the indication of expected operating temperature of each particular component and a stored value relating expected operating temperature of each particular component to the lifetime of the particular component to derive a second indication representing the expected lifetime of each particular component.

- 5 **27.** The method of claim 26 further including determining the expected life of the device by combining a measure of the each second indication for all of the components.
- 10 **28.** A method of analyzing a device comprising the steps of monitoring the intensity of infrared radiation emitted from different regions of the device while the device is being stimulated to emit infrared energy above a background level, responding to the monitored intensity of the infrared radiation from the different regions to derive first data representing the temperature at the different regions by combining indications of (a) the monitored intensity of the infrared radiation for a specific region and (b) the radiation emissivity of the specific region.
- 15 **29.** The method of claim 28 wherein the emission is monitored from each region at plural times while the device is being transiently stimulated, the first data being derived for the same region in response to the monitoring at the plural times.

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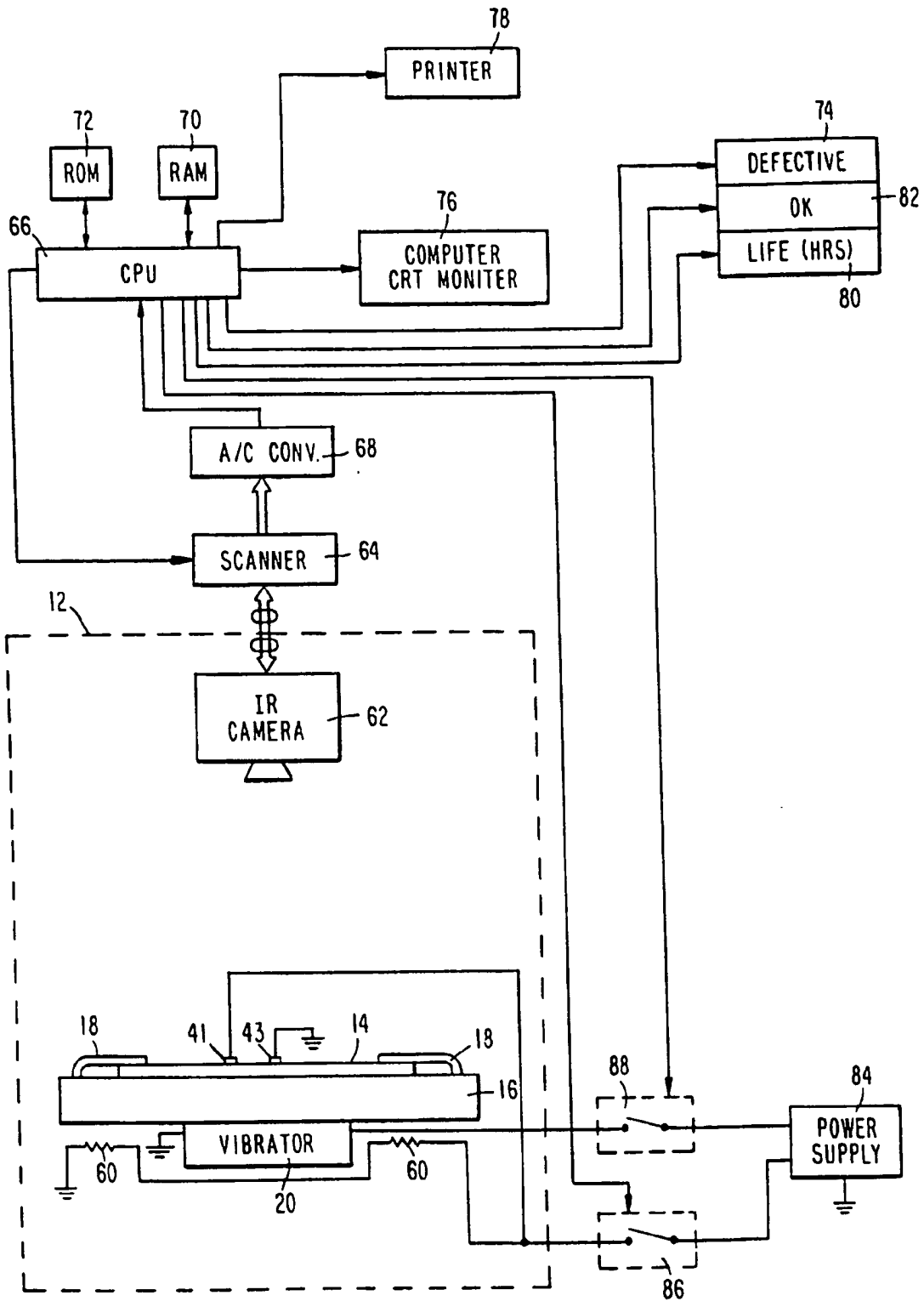


FIG. 1

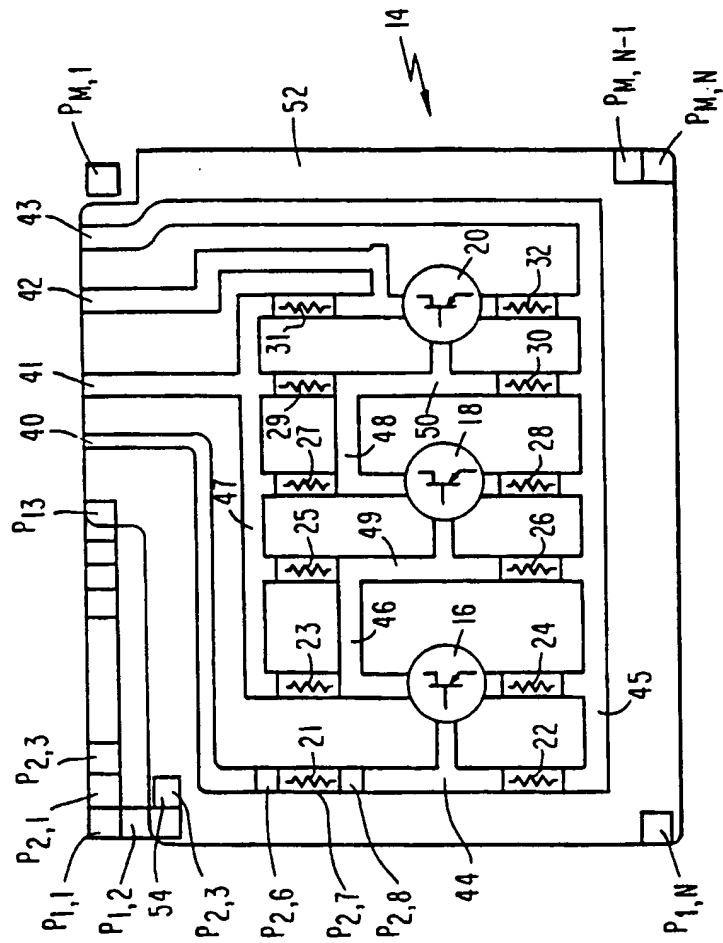
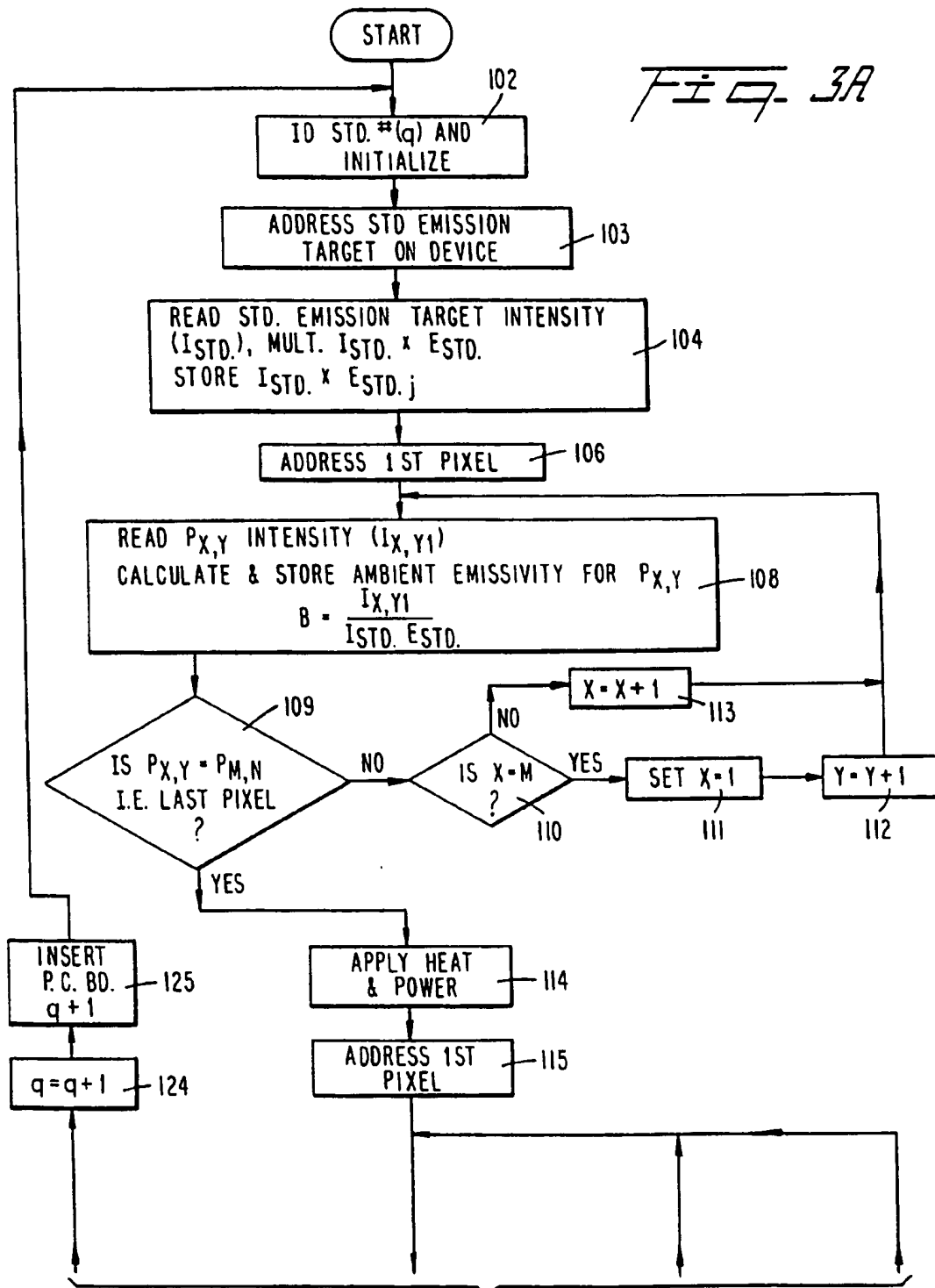
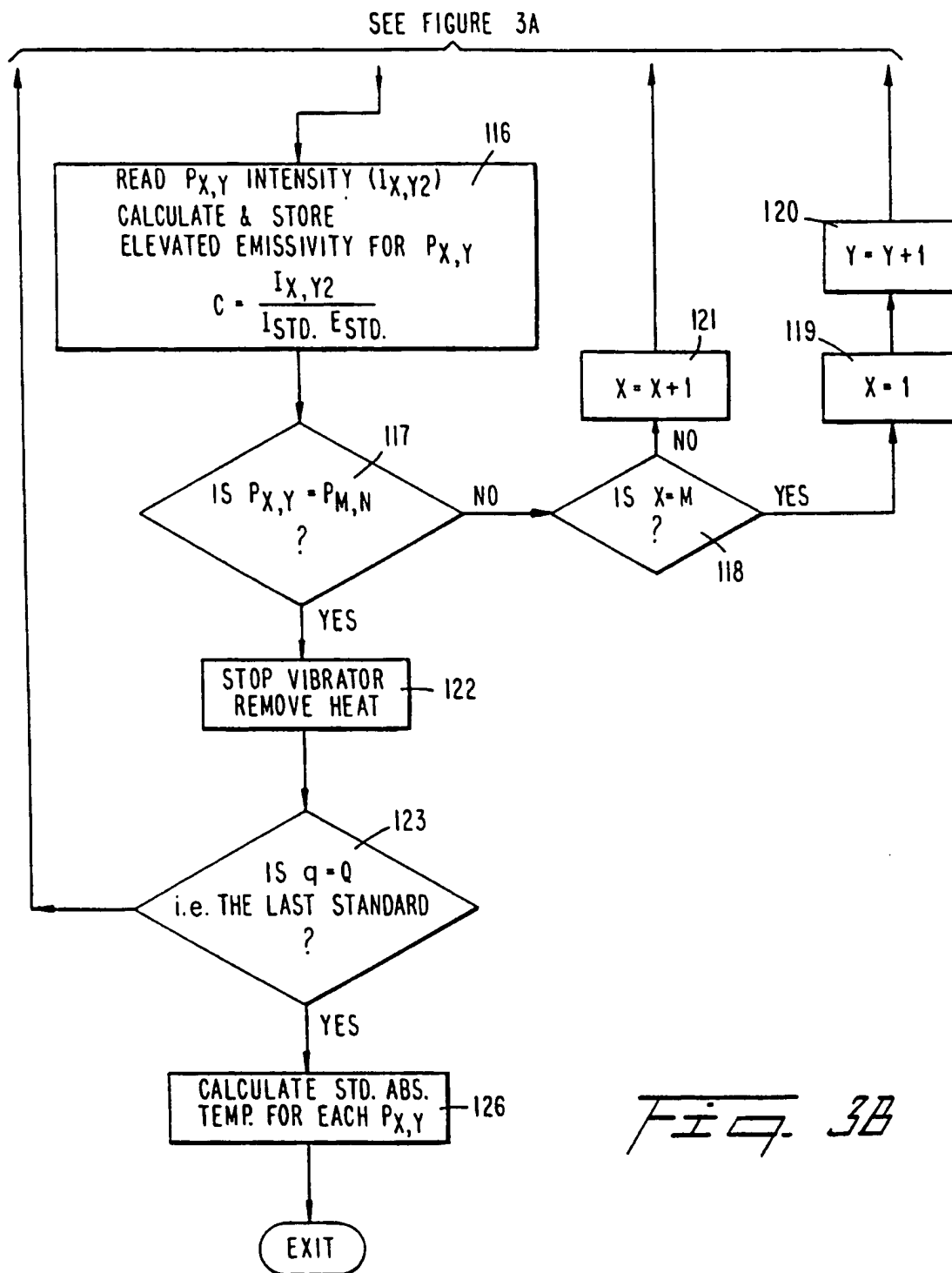


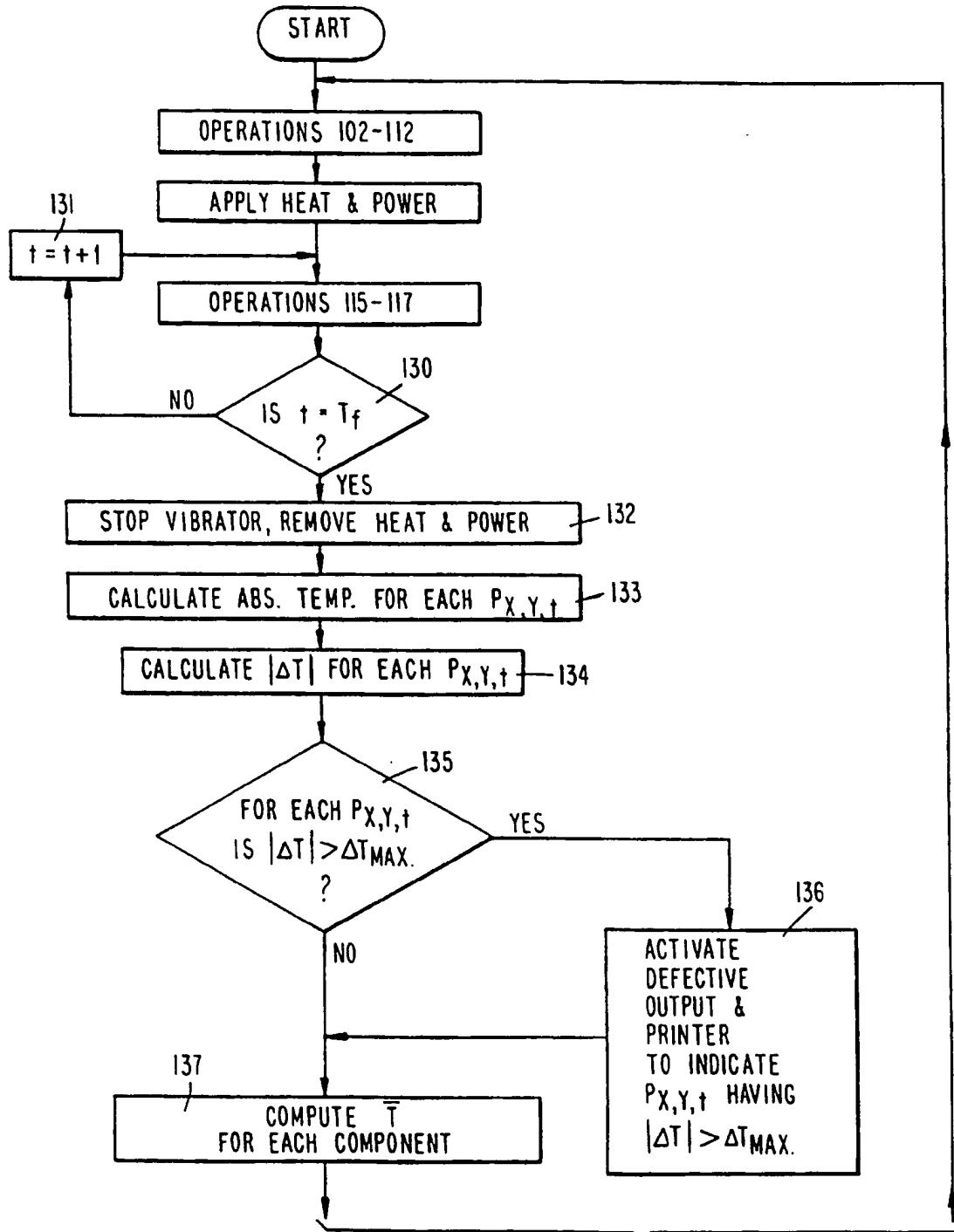
FIG. 2

FIG. 3A



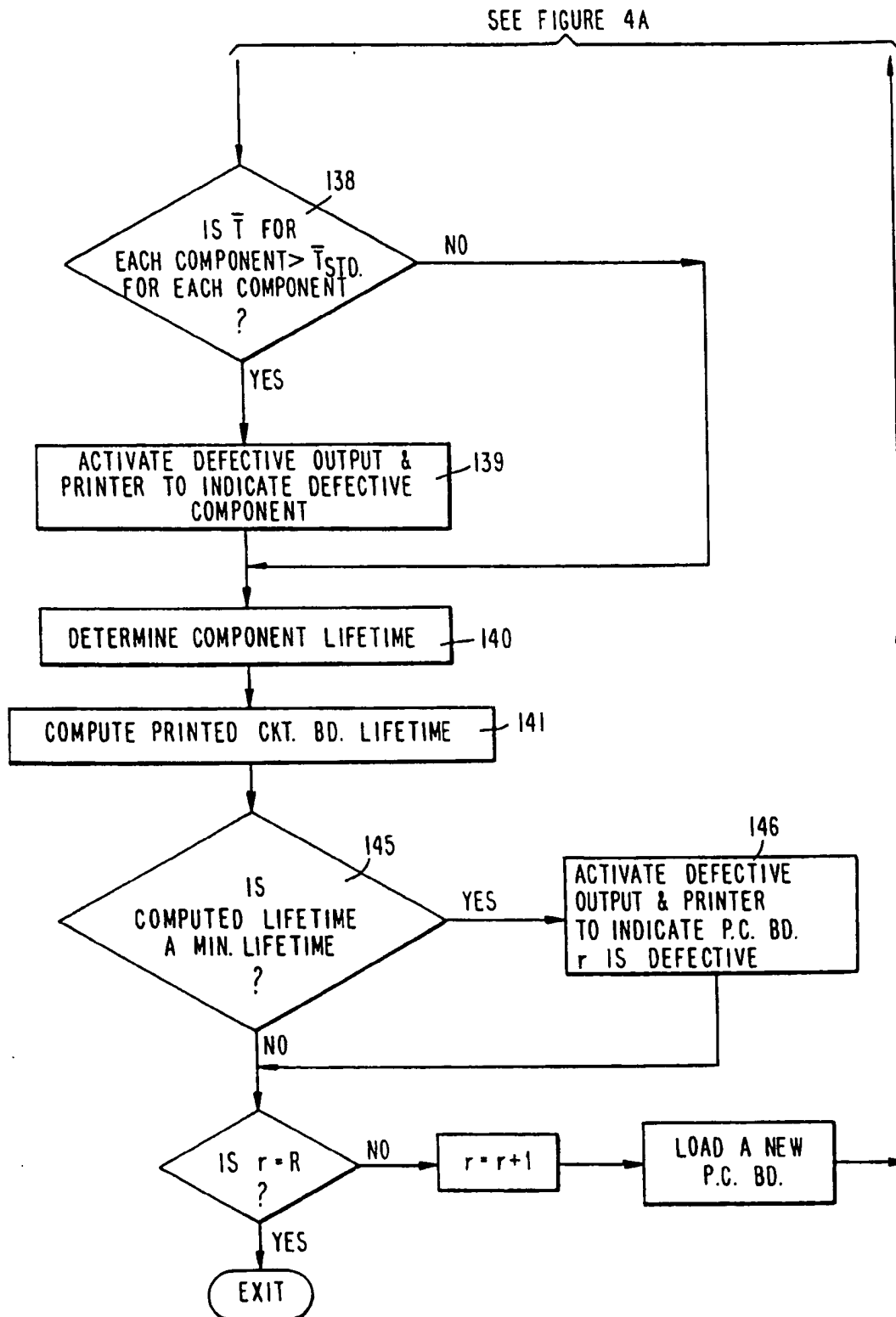
SEE FIGURE 3B





SEE FIGURE 4B

FIG. 4A

Fig. 4B



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EUROPEAN SEARCH REPORT

Application Number

EP 92 30 8794

DOCUMENTS CONSIDERED TO BE RELEVANT			
Category	Citation of document with indication, where appropriate, of relevant passages	Relevant to claim	CLASSIFICATION OF THE APPLICATION (Int. Cl.5)
X	EP-A-0 084 374 (UTI INSTRUMENTS COMPANY) * abstract * * page 2, line 5 - line 14; claims 1,2; figure 1 *	1,5,6,9	G01N25/72
A	US-A-5 032 727 (DIGITAL EQUIPMENT) * abstract * * column 3, line 18 - line 48; figure 1 *	1,2,5,7,9	
A	US-A-3 889 053 (WESTINGHOUSE ELECTRIC CORPORATION) * abstract; figure 1 *	1,5,6,9	
A	OPTICAL ENGINEERING vol. 30, no. 1, January 1991, BELLINGHAM pages 117 - 125, XP173788 X.MALDAGUE ET. AL. 'Subsurface flaw detection in reflective materials by thermal transfer imaging' * abstract * * page 120, right column - page 121, right column *	9-11	
			TECHNICAL FIELDS SEARCHED (Int. Cl.5)
			G01N
The present search report has been drawn up for all claims			
Place of search THE HAGUE		Date of completion of the search 05 JANUARY 1993	Examiner KEMPF G.V.
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